

# IKW30N65ES5XKSA1

## IKW30N65ES5XKSA1 Information

www.inclosed.com	 IKW30N65ES5XKSA1 Infineon Technologies Discrete Semiconductor Products Transistors - IGBTs - Single IGBT 650V 30A FAST DIODE TO247-3 TO-247-3 For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# IKW30N65ES5XKSA1 Specifications

Manufacturer Part Number	IKW30N65ES5XKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-247-3
Series	TrenchStop?
IGBT Type	Trench
Voltage - Collector Emitter Breakdown (Max)	650V
Current - Collector (Ic) (Max)	62A
Current - Collector Pulsed (Icm)	120A
Vce(on) (Max) @ Vge, Ic	1.7V @ 15V, 30A
Power - Max	188W
Switching Energy	560µJ (оп), 320µJ (off)
Input Type	Standard
Gate Charge	70nC
Td (on/off) @ 25°C	17ns/124ns
Test Condition	400V, 30A, 13 Ohm, 15V
Reverse Recovery Time (trr)	75ns
Operating Temperature	-40°C ~ 175°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-247-3
Supplier Device Package	PG-TO247-3
	Report errors?

### IKW30N65ES5XKSA1 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### IKW30N65ES5XKSA1 Payment Methods



If you have any question about IKW30N65ES5XKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com